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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-GBPC2502A</u>

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Datasheet of VS-GBPC2502A - RECT BRIDGE 1-PH 200V 25A GBPC-A

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VS-GBPC.. Series

Vishay Semiconductors

Single Phase Bridge (Power Modules), 25 A, 35 A





GBPC...A

GBPC...W

PRODUCT SUMMARY				
I ₀	25 A, 35 A			
V_{RRM}	200 V to 1200 V			
Package	GBPCA, GBPCW			
Circuit	Single phase bridge			

FEATURES

- Universal, 3 way terminals: push-on, wrap around or solder
- · High thermal conductivity package, electrically insulated case



- · Positive polarity symbol molded on the plastic case
- Center hole fixing
- · Glass passivated diode chips
- Excellent power/volume ratio
- Nickel plated terminals solderable using lead (Pb)-free solder; Solder Alloy Sn/Ag/Cu (SAC305); Solder temperature 260 °C to 275 °C
- Wire lead version available
- UL E300359 approved



- Designed and qualified for industrial and consumer level
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES GBPC25	VALUES GBPC35	UNITS	
1		25	35	А	
lo lo	T _C	60	55	°C	
I _{FSM}	50 Hz	400	475	Δ.	
	60 Hz	420	500	A	
l ² t	50 Hz	790	1130	A ² s	
	60 Hz	725	1030	A-S	
V _{RRM}	Range	200 to 1200		V	
T _J		-55 to	+150	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK AC REVERSE VOLTAGE $T_J = T_J$ MAXIMUM V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK AC REVERSE VOLTAGE $T_J = T_J$ MAXIMUM V	$\begin{aligned} & I_{RRM} \text{ MAXIMUM} \\ & \text{AT RATED } V_{RRM} \\ & T_J = T_J \text{ MAXIMUM} \\ & \text{mA} \end{aligned}$	I _{RRM} MAXIMUM DC REVERSE CURRENT AT T _J = 125 °C μΑ	
	02	200	275			
VS-GRPC25 A (1)	/S-GBPC25A (1) 04 /S-GBPC35A (1) 06	400	500		500	
VS-GBPC35A (1)		600	725	2		
VS-GBPC25W	08	800	900	2		
VS-GBPC35W	10	1000	1100			
	12	1200	1300			

Note

⁽¹⁾ See Ordering Information table at the end of datasheet



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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES GBPC25	VALUES GBPC35	UNITS	
	Io	Resistive or inductive load		25	35	А	
Maximum DC output current at case temperature		Capacitive load		20	28		
at case temperature					60	55	°C
		t = 10 ms	No voltage		400	475	А
Maximum peak, one-cycle non-repetitive forward current		t = 8.3 ms	reapplied		420	500	
	I _{FSM}	t = 10 ms	100 % V _{RRM}		335	400	
		t = 8.3 ms	reapplied		350	420	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage	Initial $T_J = T_J$ maximum	790	1130	A ² s
		t = 8.3 ms	reapplied		725	1030	
		t = 10 ms	100 % V _{RRM}		560	800	
		t = 8.3 ms	reapplied		512	730	
Maximum I ² √t for fusing	I ² √t	I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$; $0.1 \le t_x \le 10$ ms, $V_{RRM} = 0$ V		7.9	11.3	kA²√s	
Low level of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J maximum		0.76	0.77	V	
High level of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)})$, T_J maximum		0.89	0.92	V	
Low level forward slope resistance	r _{t1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J maximum		8.2	4.852	0	
High level forward slope resistance	r _{t2}	$(I > \pi \times I_{F(AV)}), T_J$ maximum		6.8	3.867	mΩ	
Maximum forward voltage drop	V_{FM}	$T_J = 25$ °C, $I_{FM} = I_{Favg (arm)}$		1.1	1.1	V	
Maximum DC reverse current	I _{RRM}	T _J = 25 °C, per diode at V _{RRM}		$_{\rm J}$ = 25 °C, per diode at $V_{\rm RRM}$ 5.0		.0	μΑ
RMS isolation voltage base plate	V _{INS}	f = 50 Hz, t = 1 s		f = 50 Hz, t = 1 s 2700		00	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES GBPC25	VALUES GBPC35	UNITS
Junction and storage temperature range	T _J , T _{Stg}		-55 to	+150	°C
Maximum thermal resistance, junction to case per bridge	R_{thJC}	DC operation	1.7	1.4	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	smooth, flat and greased 0.2		IV VV
Approximate weight			1	6	g
Mounting torque ± 10 %		Bridge to heatsink	2	.0	N · m (lbf · in)

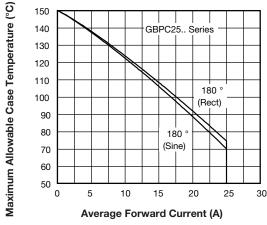


Fig. 1 - Current Ratings Characteristics

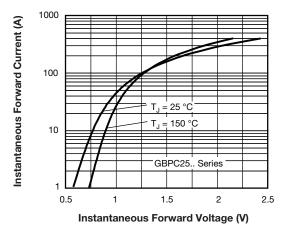


Fig. 2 - Forward Voltage Drop Characteristics

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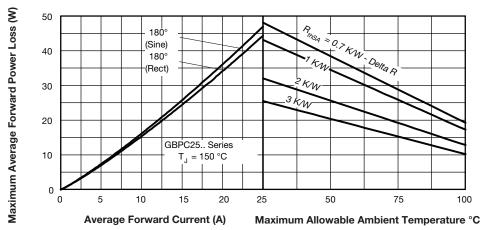


Fig. 3 - Total Power Loss Characteristics

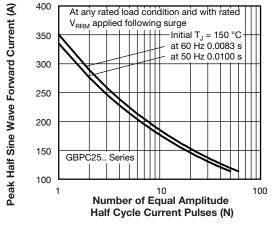


Fig. 4 - Maximum Non-Repetitive Surge Current

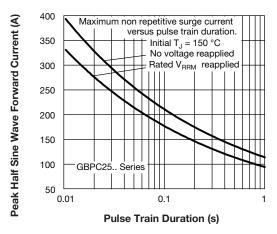


Fig. 5 - Maximum Non-Repetitive Surge Current

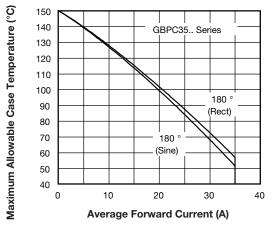


Fig. 6 - Current Ratings Characteristics

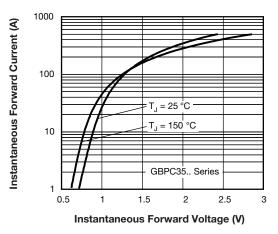


Fig. 7 - Forward Voltage Drop Characteristics





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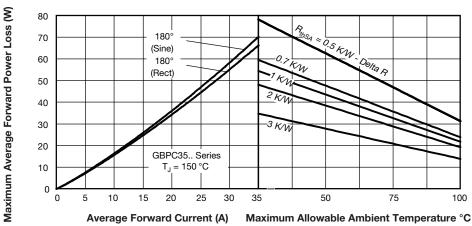
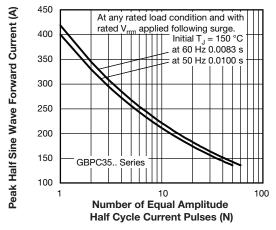


Fig. 8 - Total Power Loss Characteristics



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Fig. 9 - Maximum Non-Repetitive Surge Current

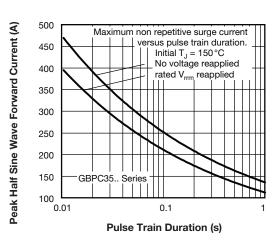


Fig. 10 - Maximum Non-Repetitive Surge Current

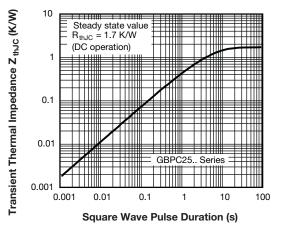


Fig. 11 - Thermal Impedance Z_{thJC} Characteristic

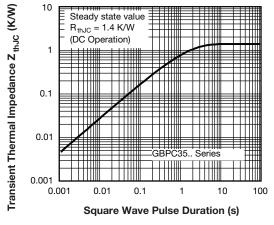


Fig. 12 - Thermal Impedance Z_{thJC} Characteristic

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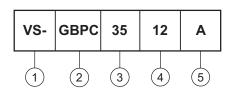


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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Circuit configuration:

Single phase bridge coding

Current rating code

25 = 25 A (average) 35 = 35 A (average)

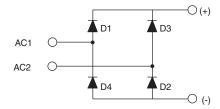
Voltage code x 100 = V_{RRM}

Diode bridge rectifier:

• A = standard fast-on terminal

W = wire lead

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95331			

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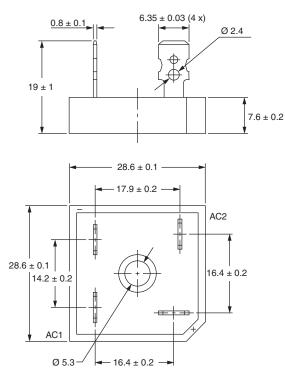


Outline Dimensions

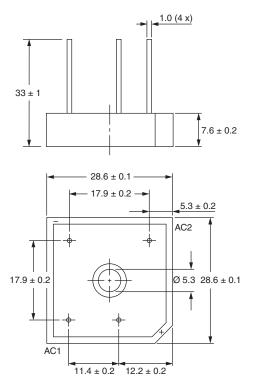
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GBPC

DIMENSIONS FOR GBPC...A in millimeters



DIMENSIONS FOR GBPC...W in millimeters



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